

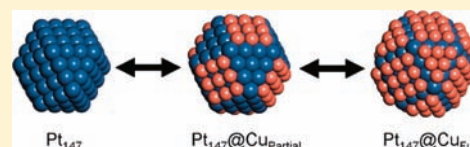
Site-Selective Cu Deposition on Pt Dendrimer-Encapsulated Nanoparticles: Correlation of Theory and Experiment

Emily V. Carino,^{†,‡,§} Hyun You Kim,^{†,§,||} Graeme Henkelman,^{†,§,||,*} and Richard M. Crooks^{*,†,‡,§}

[†]Department of Chemistry and Biochemistry, [‡]Center for Electrochemistry, [§]Texas Materials Institute, and ^{||}Institute for Computational and Engineering Sciences, The University of Texas at Austin, 1 University Station, A5300 Austin, Texas 78712-0165, United States

Supporting Information

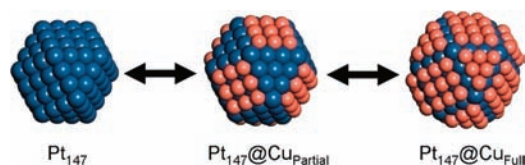
ABSTRACT: The voltammetry of Cu underpotential deposition (UPD) onto Pt dendrimer-encapsulated nanoparticles (DENs) containing an average of 147 Pt atoms (Pt₁₄₇) is correlated to density functional theory (DFT) calculations. Specifically, the voltammetric peak positions are in good agreement with the calculated energies for Cu deposition and stripping on the Pt(100) and Pt(111) facets of the DENs. Partial Cu shells on Pt₁₄₇ are more stable on the Pt(100) facets, compared to the Pt(111) facets, and therefore, Cu UPD occurs on the 4-fold hollow sites of Pt(100) first. Finally, the structures of Pt DENs having full and partial monolayers of Cu were characterized in situ by X-ray absorption spectroscopy (XAS). The results of XAS studies are also in good agreement with the DFT-optimized models.



INTRODUCTION

In this paper we show that underpotential deposition (UPD) of a Cu shell onto 1.7-nm-diameter Pt dendrimer-encapsulated nanoparticles (DENs)^{1–3} synthesized within sixth-generation, hydroxyl-terminated (G6-OH) poly(amidoamine) (PAMAM) dendrimers occurs via a two-step process corresponding to facet-specific deposition (Scheme 1). Specifically, we compared

Scheme 1



data obtained using first-principles computations with experimental electrochemical and in situ spectroscopic studies of the deposition and stripping of a Cu shell on Pt DENs consisting of an average of just ~147 atoms, denoted G6-OH(Pt₁₄₇). The results indicate that Cu deposits first onto the Pt(100) facets of G6-OH(Pt₁₄₇), followed by deposition onto the Pt(111) facets. These findings are significant for the following three reasons. First, we demonstrate that DENs provide a good nanoparticle model for direct comparison of experimental and theoretical findings. This is because they are large enough to characterize experimentally but contain few enough atoms to enable DFT calculations. Second, it is remarkable that UPD can be used to preferentially deposit a partial shell of Cu on individual facets consisting of just 16 Pt atoms. This level of precision provides a route for directly correlating first-principles calculations to complex, but well-defined, nanoparticles consisting of small numbers of atoms. Third, we demonstrate that results from density functional theory (DFT) provide mechanistic insights

into the UPD process that are highly correlated to the shape of cyclic voltammograms (CVs) for Cu UPD onto Pt DENs.

We have previously shown that UPD of Cu onto Au and Pt DENs can be used as a synthetic route to core@shell nanoparticles.^{4,5} In this approach, monometallic DENs consisting of Au or Pt were synthesized and immobilized onto electrodes, and a Cu shell was deposited via UPD. This resulted in Au@Cu or Pt@Cu DENs. With regard to the Au@Cu DENs, we found that the Cu shell could be galvanically exchanged for Pt and that the resulting Au@Pt DENs were electrocatalytically active for the oxygen reduction reaction (ORR).⁴ In the case of Pt@Cu DENs, we examined UPD of Cu onto three different sizes of Pt DEN cores. CVs for Cu UPD onto the largest of these, G6-OH(Pt₂₂₅), revealed two well-defined reduction waves, suggesting that deposition of the Cu shell takes place in two steps.⁵ Pt nanoparticles composed of 225 atoms can form closed-shell truncated octahedra, which are face-centered cubic (fcc) crystal structures presenting Pt(100) and Pt(111) facets.⁶ Therefore, we considered that the two voltammetric waves observed during Cu UPD might correspond to discrete deposition onto these two different orientations. This study also suggested that Cu deposition does not occur on edge or corner atoms of the Pt core.⁵

There is extensive literature relating to Cu UPD onto well-defined Pt surfaces.^{7–10} One key result to emerge from this literature is that Cu UPD is more energetically favorable on the Pt(100) surface compared to Pt(111).^{8,9} This is due to the lower coordination of Pt atoms on the (100) surface as compared to the close-packed (111) orientation.¹⁰ There are also several very interesting reports involving Cu UPD onto stepped Pt surfaces that are highly relevant to UPD onto

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nanoparticles.^{11–15} For example, a Pt(311) surface is composed of terraces having two rows of (111) atoms separated by (100) monatomic steps. On this surface it was found that UPD occurs first on the (111) terraces and then on (100) step sites.⁸ A related study focused on the opposite case: Pt surfaces with (111) steps and (100) terraces.¹⁰ Here it was found that Cu UPD occurred first on the (100) terraces. Clearly, results of this type are related to the ~ 1.7 nm DENs discussed here, which have facets comprised of just 16 and 10 atoms in the (100) and (111) orientations, respectively.

A number of studies predating our work have described the UPD of metal shells onto nanoparticles that are substantially larger (4–20 nm)^{16–23} than the 1.7 nm DENs reported here. For example, Adzic and co-workers deposited full Pt shells onto PdCo alloy nanoparticles having diameters of 4.6 nm. These nanoparticles were synthesized by UPD of Cu onto a PdCo core, followed by galvanic exchange of Cu for Pt. The authors found that the portions of the Pt shell that resided on the (111) orientation of the PdCo core were the most active for the ORR.²¹

Several studies have reported the synthesis of partial (submonolayer) shells on nanoparticles using alternative (non-UPD) means of shell deposition. For example, Sanchez-Cortes and co-workers chemically reduced submonolayer quantities of Pt onto 15 nm Au nanoparticles and found that the Pt shell preferentially formed submonolayer islands oriented in the (111) direction.²³ Adzic and co-workers have also synthesized Pt submonolayers on commercially available 2.5 nm Ru nanoparticles.¹⁹ In this case, the Pt submonolayer was formed via spontaneous electroless deposition of Pt on the surface of the Ru nanoparticles. This resulted in a partial shell constituting approximately 1/9 monolayer of Pt. Finally, Feliu and co-workers showed that hydroquinone adlayers reversibly adsorb onto the Pt(111) facets of 6 nm Pt nanoparticles, but irreversible adsorption occurs on Pt(100) and Pt(110) facets.²⁴

In the present study, we provide experimental and computational evidence that UPD of Cu onto G6-OH(Pt₁₄₇) DENs in a Cu²⁺-containing 0.10 M H₂SO₄ electrolyte occurs in two steps: first onto the Pt(100) facets and then onto Pt(111). The Pt@Cu DENs with full and partial Cu shells were prepared via Cu UPD onto G6-OH(Pt₁₄₇). The full and partial shell structures were characterized by voltammetry and in situ X-ray absorbance spectroscopy (XAS), and the experimental results are compared with computational models generated using DFT and molecular dynamics (MD) simulations. We find that DFT-calculated binding energies for Cu on the Pt(100) and Pt(111) facets of a “solvated” nanoparticle model, in which SO₄ ligands adsorb to the surface to mimic the solvent–surface interactions used in the experiments, correspond well with peaks observed in the CVs of Cu UPD onto G6-OH(Pt₁₄₇) DENs. In contrast, the same calculations performed on a naked, SO₄-free (solvent-free) nanoparticle model did not fit the electrochemical data. Finally, XAS results confirmed that the partial Cu shell is more stable on the Pt(100) facet, as opposed to the Pt(111) facet, in accordance with predictions from DFT.

EXPERIMENTAL SECTION

Chemicals and Materials. G6-OH dendrimers were purchased from Dendritech, Inc. (Midland, MI) as 5.0 wt % solutions in methanol. Prior to use, the methanol was removed under vacuum and the dendrimers were redissolved in sufficient water to yield a 0.10 mM solution. Unless otherwise noted, Millipore water (Milli-Q Gradient PF-06073) was used to prepare all aqueous solutions. K₂PtCl₄, CuSO₄,

LiClO₄, NaBH₄, and Ultrex ultrapure H₂SO₄ (18.76 M) were purchased from Sigma-Aldrich (Milwaukee, WI). These reagents were used as received without further purification. Two types of working electrodes were used in this study: (1) a 3-mm-diameter, glassy carbon (GC) disk electrode (CH Instruments, Austin, TX) and (2) AvCarb p75 carbon fiber paper (Ballard Materials Products, Lowell, MA). A Hg/Hg₂SO₄ reference electrode was purchased from CH Instruments. Unless otherwise noted, all potentials were measured vs Hg/Hg₂SO₄ but are reported vs NHE to maintain consistency with the literature. Compressed Ar (Praxair) was used as received.

Synthesis and Characterization of G6-OH(Pt₁₄₇@Cu) DENs.

The precise definitions of full- and partial-shell Cu UPD layers will be discussed in the Results and Discussion section, but for now it is sufficient to say that G6-OH(Pt₁₄₇) DENs having maximum Cu UPD coverage are denoted as G6-OH(Pt₁₄₇@Cu_{full}) and that DENs having less-than-maximum coverage are denoted as G6-OH(Pt₁₄₇@Cu_{partial}).

The synthesis of G6-OH(Pt₁₄₇@Cu_{full}) DENs and subsequent electrochemical measurements using the DEN-modified GC electrodes were made using a polycarbonate flow cell, which enables the exchange of solutions without emersing the electrodes (Supporting Information, Figure S1). Because the electrodes remain in contact with electrolyte while the solutions are exchanged, the working electrode can be maintained under potential control. This is an important provision, because it is necessary to remove free Cu²⁺ ions from the cell following the synthesis of full and partial shells to prevent them from electrodepositing on the electrode during subsequent electrochemical measurements.

The preparation of G6-OH(Pt₁₄₇@Cu_{full}) DENs on GC electrodes was carried out as previously described.^{5,25–27} Briefly, G6-OH(Pt₁₄₇) DENs were synthesized in water in two steps. First, 147 equiv of K₂PtCl₄ was mixed with 1.0 equiv of G6-OH dendrimer to yield a complex (G6-OH(Pt²⁺)₁₄₇). Second, this complex was reduced using a 10-fold excess of NaBH₄ with respect to Pt²⁺ to yield zerovalent G6-OH(Pt₁₄₇) DENs.²⁸ The resulting DENs were then purified by dialysis against water for 24 h.

DENs were immobilized onto the GC working electrodes using a previously described procedure.^{25,26} Briefly, the GC disk electrodes were prepared by successive mechanical polishing with 1.0, 0.3, and 0.05 μm alumina, ultrasonication in a 1:1 water–ethanol mixture for 1 min, and finally electrochemical anodizing in 0.10 M NaOH.^{5,29} Next, Pt DENs were attached to the GC working electrodes by cycling the potential three times between 0.24 and 1.24 V in a solution containing the DENs and 0.10 M LiClO₄. The DEN-modified GC working electrode, GC counter electrode, and Hg/Hg₂SO₄ reference electrode were then configured in the flow cell. Finally, the surface of the DENs was cleaned using 10 consecutive potential cycles between –0.03 and 1.34 V in Ar-purged, 0.10 M H₂SO₄.⁵

After electrochemical cleaning, the solution was exchanged for Ar-purged, 0.10 M H₂SO₄ containing 0.010 M CuSO₄ by flowing 12.0 mL of the Cu²⁺-containing solution through the cell (total cell volume: 1.0 mL). Cu UPD and stripping experiments using the DENs-modified GC electrode were carried out using the following procedure. First, the electrode potential was stepped from the open circuit potential (OCP) to 0.64 V for 150 s.⁵ Second, the potential was swept from 0.64 to 0.84 V, negative to 0.29 V, and then returned to 0.84 V. For some additional experiments relating to the electrochemical properties of G6-OH(Pt₁₄₇@Cu_{full}) and G6-OH(Pt₁₄₇@Cu_{partial}) DENs, the shell was deposited somewhat differently: by stepping, rather than sweeping, the working electrode potential from OCP to 0.29 V, the potential at which a full Cu shell is deposited on the DENs (denoted V_{full}), and holding the potential there for at least 300 s.⁵ Next, while continuing to hold the potential at V_{full}, free Cu²⁺ was removed from the cell by flushing it with 12.0 mL of Ar-purged, Cu²⁺-free, 0.10 M H₂SO₄. The removal of Cu²⁺ from the flow cell was confirmed in a separate control experiment (Supporting Information, Figure S2).

Following the syntheses of G6-OH(Pt₁₄₇@Cu_{full}) on GC electrodes via a potential step to V_{full}, the electrodes were used to record CVs in the hydrogen adsorption (H_{UPD}) potential range. This experiment was carried out as follows. Immediately after the synthesis of the Cu-coated DENs and subsequent removal of Cu²⁺, and without returning to the

OCP, the cell potential was cycled once from 0.29 V (V_{full}) to -0.03 V and back to 0.29 V. Next, the potential was stepped from V_{full} to a slightly more positive potential, 0.34 V, denoted V_{partial} , and held there for 300 s. Then, while continuing to hold the potential at V_{partial} 12.0 mL of fresh 0.10 M H_2SO_4 solution was flowed through the cell as described above. The potential was next stepped from V_{partial} to 0.29 V and was then cycled again between 0.29 V and -0.03 V to record the H_{UPD} on $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{partial}})$ DENs. This procedure was repeated using the following potentials for V_{partial} : 0.34 V, 0.39 V, 0.44 V, 0.49, 0.54 V, and 0.64 V. Lastly, the potential was stepped from V_{full} to 0.84 V (V_{bare}) and the H_{UPD} current was recorded on naked $\text{G6-OH}(\text{Pt}_{147})$ DENs.

In Situ XAS. The preparation of DEN samples for in situ XAS analysis is discussed elsewhere.⁵ Briefly, however, the AvCarb carbon paper electrodes were rendered hydrophilic by cycling their potentials eight times between 1.64 V and -0.37 V in 0.50 M H_2SO_4 before soaking them in solutions of dialyzed $\text{G6-OH}(\text{Pt}_{147})$ for at least 12 h.^{5,27} The DEN-modified AvCarb electrodes were then configured in a custom-designed cell for in situ XAS experiments. Finally, the DENs were cleaned electrochemically using 10 consecutive potential cycles between -0.15 and 0.84 V.^{5,27}

In-situ XAS data were obtained using the DEN-modified AvCarb electrode poised at each of the following three potentials: (1) $V_{\text{full}} = 0.26$ V (in the in situ cell); (2) $V_{\text{partial}} = 0.41$ V, which corresponds to a partial Cu UPD monolayer; and (3) $V_{\text{bare}} = 0.84$ V, a potential at which Cu does not deposit on $\text{G6-OH}(\text{Pt}_{147})$. These potentials were chosen on the basis of voltammetry corresponding to Cu stripping from $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{full}})$ and $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{partial}})$ DENs (Supporting Information, Figure S3).

XAS data were acquired as follows. First, spectra were collected at V_{bare} . Second, a full Cu shell was deposited by stepping the electrode potential from V_{bare} to V_{full} . Third, the working electrode was taken out of potential control for ~ 1 min while the solution was exchanged for Cu^{2+} -free 0.10 M H_2SO_4 . As mentioned earlier, this prevents free Cu^{2+} from interfering with the spectrum of the immobilized DENs. Note that we have previously shown that the solution exchange procedure does not compromise the Cu shells.⁵ Fourth, the cell potential was returned to V_{full} and held there while XAS spectra were recorded. After collecting XAS spectra with the electrode poised at V_{full} , the potential was stepped from V_{full} to V_{partial} and held there while collecting additional XAS scans. Finally, the Cu shell was removed by sweeping the potential from V_{partial} to V_{bare} and additional XAS spectra were collected.

Characterization. Transmission electron microscope (TEM) images were obtained at 200 keV in bright-field mode using a JEOL 2010F TEM. X-ray photoelectron spectroscopy (XPS) spectra were obtained using a Kratos Axis Ultra spectrometer equipped with an Al $K\alpha$ radiation source. Spectra were collected at a pass energy of 20 eV and a step size of 0.5 eV. CVs using GC electrodes were obtained using a CHI 760B potentiostat (CH Instruments). The in situ XAS experiments were carried out using a WaveNow hand-held potentiostat (Pine Instruments, Grove City, PA).

XAS experiments were performed at beamline X18B of the National Synchrotron Light Source at Brookhaven National Laboratory. In-situ data were obtained with the working electrode under potential control using a previously described spectroelectrochemical cell.^{5,27} The XAS spectra were collected in fluorescence mode using an Ar-filled, five-grid Lyttel detector, whereas reference spectra were obtained using Pt and Cu foils and collected in transmission mode. Prior to being fit, the X-ray absorbance edges for the in situ XAS data were aligned in energy with those for the reference foil spectra. XAS data were analyzed using the IFEFFIT6 sixPACK, ATOMS, and Horae software packages.^{30–32} This software is available at no charge through the Consortium for Advanced Radiation Sources and is accessible online at <http://cars9.uchicago.edu/ifeffit/Downloads>.

Density Functional Theory Calculations. Four models, shown in Figure 1, were used to study Cu deposition and stripping on Pt DENs: (1) a cuboctahedral Pt nanoparticle consisting of 147 Pt atoms, denoted $\text{Pt}_{147}^{\text{DFT}}$; (2) a SO_4 ligand-covered half-nanoparticle, denoted $(\text{SO}_4)\text{Pt}_{147}^{\text{DFT-half}}$; (3) a nanoparticle model representing the $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{full}})$ DENs, denoted $\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT}}$; and (4) a SO_4 ligand-covered half-nanoparticle model, denoted $(\text{SO}_4)\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT-half}}$.

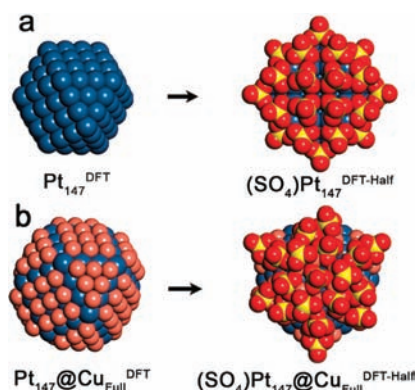


Figure 1. DFT-optimized (a) $\text{Pt}_{147}^{\text{DFT}}$ and $(\text{SO}_4)\text{Pt}_{147}^{\text{DFT-half}}$ and (b) $\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT}}$ and $(\text{SO}_4)\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT-half}}$ models. These models were used in the DFT studies of the Cu deposition and stripping processes.

$\text{OH}(\text{Pt}_{147}@\text{Cu}_{\text{full}})$ DENs, denoted $\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT}}$; and (4) a SO_4 ligand-covered half-nanoparticle model, denoted $(\text{SO}_4)\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT-half}}$.

The models with SO_4 ligands were used to investigate the effect of counterions from the solution on the energetics of Cu deposition and stripping. Half-nanoparticles were modeled to reduce the computational cost associated with the large number of atoms involved. In test cases of Cu deposition and stripping, we found that the half-particle approximation changed the binding of Cu by less than 0.1 eV as compared to the full particle. The $\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT}}$ model contained 102 Cu atoms, 6 and 9 on the Pt(111) and Pt(100) facets, respectively. The $(\text{SO}_4)\text{Pt}_{147}^{\text{DFT-half}}$ model contained 20 SO_4 ligands, 3 on each Pt(111) facet, 4 on the Pt(100) facet, and 4 on the remaining portion of the Pt(111) facet. The $(\text{SO}_4)\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT-half}}$ model contained 19 SO_4 ligands: 1 on each Cu(111) facet, 3 on each Cu(100) facet, and 9 on the Pt–Cu interface.

Calculations of the binding energy of Cu to the Pt nanoparticle were compared with the experimental CV data. The electrochemical potential for depositing Cu onto the Pt DENs was related to the energy gained by adsorbing a Cu atom onto the $\text{Pt}_{147}^{\text{DFT}}$ particle, E_{deposit} . Similarly, the stripping potential was related to the energy required to remove a Cu atom from $\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT}}$, E_{strip} . Solvent effects were evaluated by performing the same calculations on the SO_4 -covered models.

The DFT calculations were carried out in vacuum for computational efficiency, but this means that the solvation free-energy of desorbed species was missing from E_{deposit} and E_{strip} . Fortunately, the solvation energy of Cu^{2+} contributes a constant factor in the Cu adsorption or desorption process, and so it is not required for the calculation of relative binding energies with respect to a reference. Our chosen reference was the binding of Cu to $\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT}}$ ($E_{\text{deposit}}^{\text{bulk-DFT}} = -2.97$ eV), which we associated with the bulk Cu reduction potential in the electrochemical experiment, 0.24 V (Supporting Information, Figure S2). The DFT-calculated electrochemical potentials for the deposition and stripping processes are then defined as $V_{\text{deposit}}^{\text{DFT}} = 1/2(E_{\text{deposit}} - E_{\text{deposit}}^{\text{bulk-DFT}})$ and $V_{\text{strip}}^{\text{DFT}} = 1/2(E_{\text{strip}} + E_{\text{deposit}}^{\text{bulk-DFT}})$, where the factor of $1/2$ accounts for the two electron process.

The structures of the nanoparticle models were optimized with spin-polarized DFT calculations using the Vienna ab initio simulation package (VASP) code.^{33,34} Electronic exchange and correlation were modeled using the PW91 functional.³⁵ Valence electron wave functions were expanded in a plane-wave basis up to an energy cutoff of 290 eV. The ionic cores were described by the projector augmented-wave (PAW) method.³⁴ Nanoparticles were placed on the center of the $(28 \text{ \AA})^3$ cell. Structures were considered converged when the force on all atoms dropped below 0.02 eV/Å. A Fermi smearing function, with a width of 0.2 eV, was used to improve convergence with respect to states near the Fermi level.

Molecular Dynamics (MD) Simulations. The stability of Pt₁₄₇@Cu_{full}^{DFT} was evaluated by running MD simulations at 350 K using the LAMMPS package.³⁶ Interatomic forces were evaluated with the embedded atom method (EAM) many-body potential. The MD trajectory was evaluated using a time step of 1 fs for a total simulation time of 300 ns.

RESULTS AND DISCUSSION

Cu UPD onto G6-OH(Pt₁₄₇) DENs. We chose to use Pt DENs consisting of an average of 147 atoms for this study, because this number can result in a closed shell cuboctahedron. This structure has 92 Pt atoms on its surface, arranged in 6 Pt(100) facets and 8 Pt(111) facets (Scheme 1). Each Pt(100) facet consists of 16 atoms, and each Pt(111) facet consists of 10 atoms, with the edge and corner atoms being shared. These DENs have a measured diameter of 1.7 ± 0.3 nm (Supporting Information, Figure S4), which is consistent with previous reports and their calculated diameter (1.6 nm).²⁸ Before presenting the results of our study, it is important to introduce a key aspect of the nomenclature that will be used. Specifically, electrochemical potentials and binding energies will be discussed separately, and therefore, different symbols are used for each: electrochemical potentials are referred to using the symbol V , and binding energies are denoted as E .

The red line in Figure 2 is a CV, which was recorded in 0.10 M H₂SO₄ containing 0.010 M CuSO₄, showing Cu UPD onto

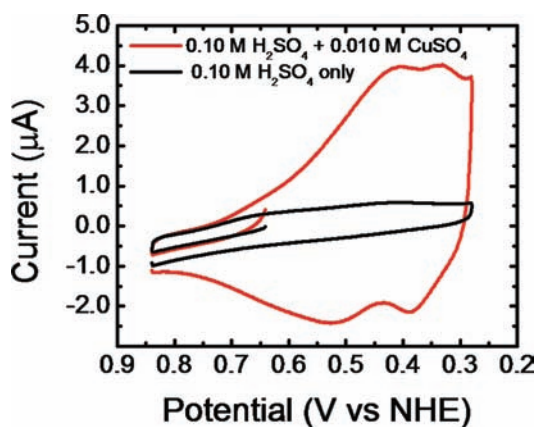


Figure 2. Voltammetry pertaining to a GC electrode modified with G6-OH(Pt₁₄₇) DENs showing Cu UPD and stripping (red) in 0.10 M H₂SO₄ + 0.010 M CuSO₄ that was deoxygenated with Ar, and the background capacitance (black) in 0.10 M H₂SO₄ only, which was also purged with Ar. Both scans began at 0.64 V and were initially swept in the positive direction at a scan rate of 10 mV/s.

and Cu stripping from G6-OH(Pt₁₄₇) DENs. Two poorly resolved reduction waves are present at 0.41 and 0.33 V, and these correspond to the deposition of the Cu shell in two steps. The potential difference between the peaks of these waves, denoted $\Delta V_{\text{deposit}}^{\text{exp}}$, is 0.08 V. Upon scan reversal, two oxidation waves appear at 0.39 and 0.53 V. These correspond to the stripping of Cu from the G6-OH(Pt₁₄₇) core in two steps. The stripping waves, while also broad, are better resolved than the deposition waves with $\Delta V_{\text{strip}}^{\text{exp}} = 0.14$ V. The background current (black line, Figure 2), which is capacitive, was obtained under the same conditions as the UPD scan except in the absence of Cu²⁺.

The peaks representing Cu UPD on these DENs are not as sharp as those typically observed for Cu UPD on high-quality Pt single-crystal electrodes. This is a consequence of the very

small facet sizes on the DENs and the fact that most of the atoms on both the (111) and (100) facets are shared. For example, only a single Pt atom on the (111) face is unshared (Scheme 1). Similarly broad Cu peaks have been reported by others for UPD onto nanoparticles.^{21,37,38} Note that lowering the voltammetric scan rate below 10 mV/s did not change the peak positions or increase their sharpness.

The electrochemical properties of G6-OH(Pt₁₄₇@Cu_{full}) and G6-OH(Pt₁₄₇) DENs in the H_{UPD} potential region were examined in 0.10 M H₂SO₄ (Supporting Information, Figure S5a). Current due to H_{UPD} dominates the CV of the G6-OH(Pt₁₄₇)-modified GC electrode, while this reaction is greatly suppressed on the G6-OH(Pt₁₄₇@Cu_{full})-modified electrode. We have previously shown that similar results are obtained on G6-OH(Pt₂₂₅) DENs with and without a Cu UPD shell.⁵ The results in Figure S5a suggest that G6-OH(Pt₁₄₇@Cu_{full}) DENs assume a well-segregated core@shell structure.

We also examined H_{UPD} on a G6-OH(Pt₁₄₇@Cu_{partial})-modified GC electrode (Supporting Information, Figure S5b). The G6-OH(Pt₁₄₇@Cu_{partial}) DENs were prepared by stripping incrementally greater amounts of the Cu shell from G6-OH(Pt₁₄₇@Cu_{full}) DENs. Removal of a small fraction of the Cu shell restores the current for only one of the two H adsorption peaks. This indicates that partial shells of Cu suppress H_{UPD} on one of the facets but not the other, and it further hints that the Cu UPD is selective for specific facets.^{9,10} In the next section, we describe how computational models were used to examine the selectivity of the deposition process.

Computational Studies of Cu UPD and Stripping on Pt DENs. An estimate of the potential at which Cu UPD occurs was made by calculating the average binding energy ($E_{\text{deposit}}^{\text{DFT}}$) of Cu atoms on the Pt(100) and Pt(111) facets of Pt₁₄₇^{DFT} using the Pt₁₄₇@Cu_{partial} and Pt₁₄₇@Cu_{full} models (Scheme 1). The average binding energy was calculated to be -3.70 eV on the Pt(100) facet and -3.33 eV on the Pt(111) facet, leading to a calculated shift in potential for deposition on the two facets of $\Delta V_{\text{deposit}}^{\text{DFT}} = 0.19$ V. Stronger binding of Cu on the Pt(100) facet is consistent with the first (most positive) UPD peak observed in Figure 2, and weaker Cu binding on the Pt(111) facet is likewise associated with the second peak. What is not captured in these average binding energy calculations is the difference in potential between deposition and stripping. For that, we require a more detailed atom-by-atom model of the deposition and stripping processes.

The calculated process for Cu deposition on Pt₁₄₇^{DFT} is shown in Figure 3a (and with more detail in Figure S6 of the Supporting Information). Deposition of Cu atoms onto the Pt(100) facet sites is energetically favorable, meaning that the binding energies of the Cu atoms are more negative compared to the Pt(111) facets. The binding energies of Cu atoms on the Pt(100) facet are similar: $E_{\text{deposit}} = -3.71$ eV for the first atom (step 1 in Figure 3a) and $E_{\text{deposit}} = -3.70$ eV for subsequent Cu atoms (Supporting Information, Figure S6). This is again consistent with the association of Cu deposition on the Pt(100) facet with the first (most positive) UPD current peak in Figure 2. The observation that the binding energy is similar for each Cu atom deposited on the Pt(100) facet demonstrates that Cu deposition onto the Pt(100) facet is dominated by Pt–Cu interactions.

After the Pt(100) facets are covered with Cu atoms, deposition begins on the Pt(111) facets. The first Cu atom on the Pt(111) facet binds with an energy $E_{\text{deposit}} = -3.07$ eV (step 3 in Figure 3a). Subsequent binding of Cu atoms to this

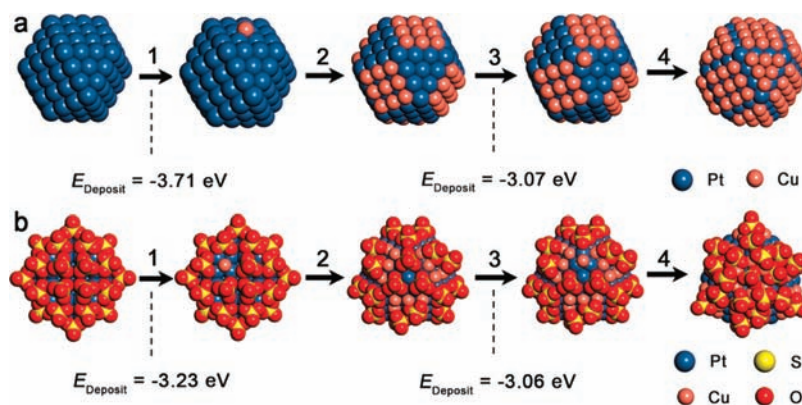


Figure 3. Cu deposition process shown with the (a) $\text{Pt}_{147}^{\text{DFT}}$ and (b) $(\text{SO}_4)\text{Pt}_{147}^{\text{DFT-half}}$ models.

facet is stronger ($E_{\text{deposit}} = -3.33$ eV) (Supporting Information, Figure S6). In other words, the first Cu deposition event on the Pt(111) facet is a “peak generating event”, because this step induces spontaneous Cu deposition on the remainder of the facet. We therefore associate the binding energy for the first Cu atom on the Pt(111) facet with the location of the second (more negative) Cu UPD peak in Figure 2. The calculated locations of these peaks are shown in Figure 4 for comparison with the experimental CV data.

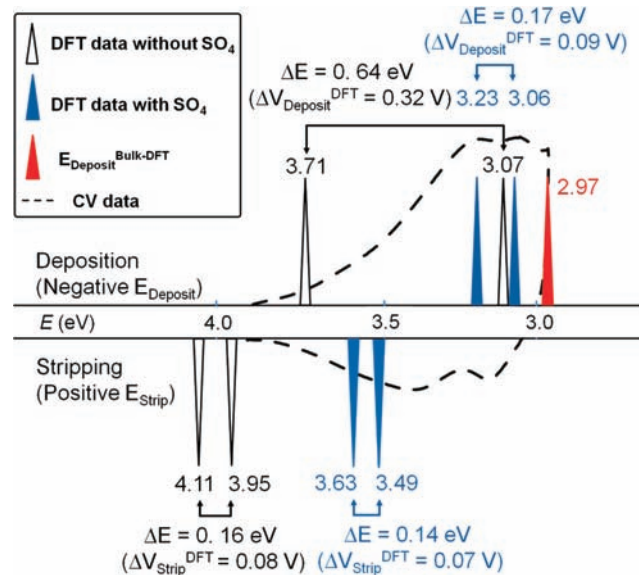


Figure 4. DFT calculated Cu deposition and stripping energies for the various models with the experimentally obtained Cu UPD CV overlaid for comparison (black dashed line).

The difference in potential for Cu deposition on the Pt(100) and Pt(111) facets, $\Delta V_{\text{deposit}}^{\text{DFT}} = 0.32$ V, is calculated from the

difference in initial binding energy on the two facets (steps 1 and 3 in Figure 3a), taking into account the two-electron transfer required for the reduction of Cu^{2+} . The measured potential difference between the Cu UPD peaks, $\Delta V_{\text{deposit}}^{\text{exp}} = 0.08$ V, is significantly smaller than the calculated value. Another difference between the calculated and experimental CV peaks is the so-called “UPD shift”, a parameter that describes the magnitude of the potential difference between the potential for Cu UPD and the bulk Cu reduction potential.^{39,40} Figure 2 shows the two deposition peaks at 0.41 and 0.33 V, which are close to the experimentally observed bulk Cu reduction potential, 0.24 V (Supporting Information, Figure S2). These UPD potentials correspond to shifts, relative to the bulk Cu reduction potential, of 0.17 and 0.09 V, respectively. The experimentally observed UPD shifts are presented in Table 1 alongside the corresponding UPD shifts calculated by DFT. The DFT calculated UPD shift for Cu deposition on the Pt(100) and Pt(111) facets of $\text{Pt}_{147}^{\text{DFT}}$ are 0.36 and 0.05 V. While the UPD shift calculated for Cu deposition on Pt(111) is in reasonable agreement with the experimentally observed value, the UPD shift corresponding to Cu UPD on the Pt(100) facet, 0.36 V, is too large compared to the experimental value. In the next section, we will show that this discrepancy can be attributed to solvent interactions with the DEN surface.

The Cu deposition calculations were repeated using SO_4 ligand-covered half-nanoparticle models (Figure 1) to evaluate the sensitivity of the Cu binding energy calculations to the presence of ligands from solution bound to the nanoparticles. Figure 3b shows the key steps in the Cu deposition process on the $(\text{SO}_4)\text{Pt}_{147}^{\text{DFT-half}}$ model. The first step in this process is the desorption of a SO_4 ligand from the Pt(100) facet of $(\text{SO}_4)\text{Pt}_{147}^{\text{DFT-half}}$. This is necessary to create space on the Pt surface to which Cu can bind (Figure 3b, step 1). The binding energy of Cu in this step was found to be $E_{\text{deposit}} = -3.23$ eV, which is significantly weaker than that calculated for the bare $\text{Pt}_{147}^{\text{DFT}}$ particle (-3.71 eV). The weaker binding energy is due

Table 1. Experimental and DFT-Calculated UPD Deposition and Stripping Potential Shifts Relative to Bulk Cu Deposition

	experimental data		DFT-calculated data			
	Pt(100)	Pt(111)	$\text{Pt}_{147}^{\text{DFT}}$ Pt(100)	Pt(111)	$(\text{SO}_4)\text{Pt}_{147}^{\text{DFT-half}}$ Pt(100)	Pt(111)
deposition						
UPD shift	0.17 V	0.09 V	0.36 V	0.05 V	0.13 V	0.05 V
stripping						
UPD shift	0.29 V	0.15 V	0.57 V	0.49 V	0.33 V	0.25 V

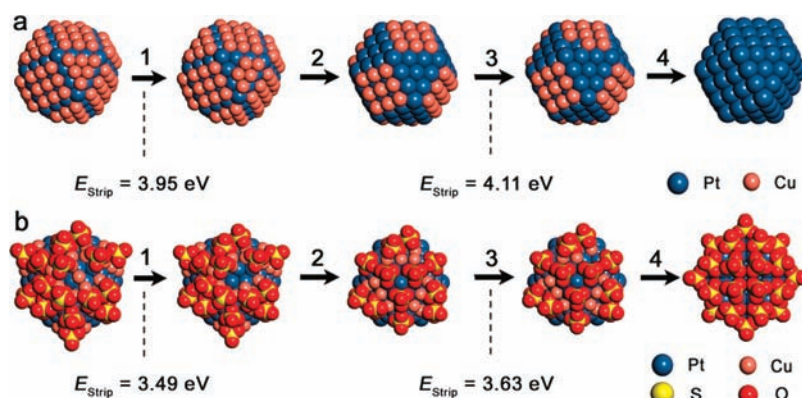


Figure 5. Cu stripping process shown on the (a) $\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT}}$ and (b) $(\text{SO}_4)\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT-half}}$ models.

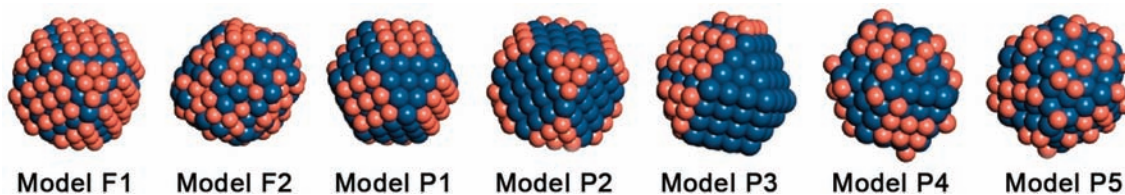


Figure 6. Structural models calculated by DFT and MD simulations for the purpose of comparing them to values extracted from fits to the XAS spectra of $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{full}})$ and $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{partial}})$. Model F1 is the full shell model generated by the deposition of Cu atoms onto both the Pt(100) and Pt(111) facets of $\text{Pt}_{147}^{\text{DFT}}$ as shown in Figure 3; Model F2 is a surface-alloyed structure that resulted when MD simulations were applied to structural model F1; Model P1 is the partial shell model generated by the deposition of Cu atoms onto only the Pt(100) facets of $\text{Pt}_{147}^{\text{DFT}}$ as shown in Figure 3; Model P2 is another partial shell model in which Cu occupies only the Pt(111) facet positions; Model P3 is a partial shell model in which the Cu atoms are arranged in a Janus-like partial shell coverage; Model P4 is a partial shell model having most of the Cu atoms deposited in the Pt(100) facets and a small degree of dispersion of the Cu shell atoms to the Pt(111) facets; Model P5 is a partial shell structure created by randomly distributing Cu atoms over the entire surface.

to saturation of the dangling Pt bonds at the surface. After depositing the first Cu atom, the binding energy of Cu atoms subsequently placed on the Pt(100) facet was found to increase, leading to barrierless Cu deposition on the remaining Pt(100) facets (Figure 3b, step 2).

On the Pt(111) facet, the SO_4 ligands are found to have a negligible effect on the initial Cu binding. This is because the initial binding site (step 3 in Figure 3b) on the small Pt(111) facet is not sterically crowded by SO_4 ligands. As before, the binding of the first Cu atom on the Pt(111) facet lowers the barrier for the deposition of subsequent Cu atoms on this facet (step 4 in Figure 3b).

The binding energies and potentials for Cu UPD onto the SO_4 -covered Pt DENs are summarized in Figure 4 and Table 1. In the presence of SO_4 ligands, the calculated UPD shifts for the Pt(100) and Pt(111) facets of the $(\text{SO}_4)\text{Pt}_{147}^{\text{DFT-half}}$ model, $V = 0.13$ and 0.05 V, respectively, are in good agreement with the corresponding experimental values of $V = 0.17$ and 0.09 V.

Cu stripping was modeled in a manner similar to that described for the UPD process, except the Cu binding energies were calculated by removing a Cu atom from the particle surface. The key steps associated with Cu stripping from the $\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT}}$ model are shown in Figure 5a. The entire process is provided separately (Supporting Information, Figure S7). The first step in this process is the removal of the lowest-coordinated Cu adatom from the corner position of the Pt(111) facet. The stripping energy, E_{strip} , for this step was calculated as 3.95 eV; subsequent stripping of Cu atoms from the Pt(111) facet (step 2) was found to be spontaneous (Supporting Information, Figure S7). Similarly, the energy required to remove the first Cu atom from the Pt(100) facet

(step 3), 4.11 eV, was the most difficult and defines the position of the stripping peak. Converting these stripping energies to potentials gives calculated UPD shifts of 0.57 and 0.49 V for the stripping of Cu from the Pt(100) and Pt(111) facets of the $\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT}}$ model (Table 1). The difference between these peak positions, $\Delta V_{\text{strip}}^{\text{DFT}} = 0.08$ V, is close to the experimental value of 0.14 V (Table 1 and Figure 4), but the magnitude of the UPD shift far exceeds the corresponding experimental values of 0.29 and 0.15 V.

To better reconcile the experimental and theoretical findings, SO_4 ligands were used to evaluate solvent interactions, thereby stripping Cu from the $(\text{SO}_4)\text{Pt}_{147}@\text{Cu}_{\text{full}}^{\text{DFT-half}}$ model. Figure 5b shows the key steps in the stripping process. The overall effect of the SO_4 ligands is to reduce the binding energy of Cu by ~ 0.5 eV. This constant reduction in binding energy can be understood as arising from saturation of the Cu dangling bonds and a subsequent weakening of the Cu–Cu and Cu–Pt interactions.

In the presence of SO_4 ligands, the calculated UPD shifts for Cu stripping are calculated to be 0.33 and 0.25 V for the Pt(100) and Pt(111) facets, respectively. These potentials are much closer to the corresponding experimentally observed UPD shifts of 0.29 and 0.15 V, illustrating the importance of ligand interactions.

In-Situ XAS Analysis of $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{full}})$ and $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{partial}})$. We turned to in situ XAS to characterize the structures of $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{full}})$ and $\text{G6-OH}(\text{Pt}_{147}@\text{Cu}_{\text{partial}})$ DENs so that these could be compared to the structural models predicted by DFT and MD simulations. In-situ characterization of these structures is necessary, because we found that Cu monolayers and submonolayers on Pt DENs are

only stable in air, or at the OCP in solution, for ~ 1 min; however, the XAS spectra are acquired over a period of about 24 h. The procedure used to carry out these spectroelectrochemical experiments was discussed in detail in the Experimental Section, but, briefly, dialyzed G6-OH(Pt₁₄₇) DEN cores were immobilized on an AvCarb carbon-paper electrode and its potential was controlled during XAS data acquisition. The samples were characterized with the electrode poised at two potentials: V_{full} , which corresponds to a full Cu UPD shell (G6-OH(Pt₁₄₇@Cu_{full})), and V_{partial} , a potential positive of V_{full} corresponding to a partial Cu shell (G6-OH(Pt₁₄₇@Cu_{partial})). The CNs obtained from fits to the XAS data can be compared to those calculated for a number of reasonable structural models, which are shown in Figure 6. The CNs calculated for the models are presented alongside the CNs extracted from the fits to the data (calculated and extracted, respectively, in Tables 2 and 3).

Table 2. CNs Extracted from Experimental, In-Situ XAS Spectra of G6-OH(Pt₁₄₇@Cu_{full}) Compared to CNs Calculated from the Full-Coverage (F) Model Structures Shown in Figure 6

coordination no. (CN) ^a	extracted CN ^c (sample)	calculated CN ^d (model F1)	calculated CN (model F2)
n_{PP}	6.7 ± 1.1	8.9	6.9
n_{PC}	2.4 ± 0.8	2.5	2.9
n_{CC}	2.7 ± 3.7	2.8	3.1
n_{CP}	3.9 ± 0.2	3.5	4.1
n_{CO}^b	0.7 ± 0.4	N/A ^e	N/A
n_{Pm}	9.1	11.4	7.8
n_{Cm}	6.6	6.3	7.2

^aCN is coordination number. ^b n_{CO} represents Cu with a low-Z nearest-neighbor. ^cExtracted CN is extracted from the fit to the data. ^dCalculated CN is estimated from the referenced DFT model. ^eN/A meaning not applicable because we did not include low-Z neighbors in the referenced models.

The radial distribution spectra of the XAS data and the computed fits for G6-OH(Pt₁₄₇@Cu_{full}) are shown in Figure 7a and b for the Pt L3 and Cu K absorbance edges, respectively. The R-space distribution and fits for G6-OH(Pt₁₄₇@Cu_{partial}) are given in Figure 7c and d, and these also show both the Pt and Cu edge data, respectively. The corresponding k-space data are provided separately (Supporting Information, Figure S8).

Table 3. CNs Extracted from Experimental, In-Situ XAS Spectra of G6-OH(Pt₁₄₇@Cu_{partial}) Compared to CNs Calculated from the Partial (P) Model Structures Illustrated in Figure 6

coordination no. (CN) ^a	extracted CN ^c (sample)	calculated CN ^d (model P1)	calculated CN (model P2)	calculated CN (model P3)	calculated CN (model P4)	calculated CN (model P5)
n_{PP}	7.5 ± 1.3	8.9	8.9	8.9	8.9	8.9
n_{PC}	1.8 ± 0.7	1.5	1.0	1.2	1.4	1.3
n_{CC}	1.5 ± 0.8	2.7	3.0	2.8	19	1.1
n_{CP}	4.9 ± 0.7	4.0	3.0	3.5	3.8	3.6
n_{CO}^b	0.3 ± 2.8	N/A ^e	N/A	N/A	N/A	N/A
n_{Pm}	9.3	10.4	9.9	10.1	10.3	10.2
n_{Cm}	6.4	6.7	6.0	6.3	5.7	4.7
R-value ^f	N/A ^g	4.4	6.9	5.6	3.8	4.2

^aCN is coordination number. ^b n_{CO} represents Cu with a low-Z nearest-neighbor. ^cExtracted CN is extracted from the fit to the data. ^dCalculated CNs are estimated from the referenced DFT models. ^e n_{CO} was not calculated because the concentration of low-Z nearest-neighbors (E) adsorbed to Cu has not been measured on Pt₁₄₇@Cu structures. ^fThe R-value describes the correlation between the data and the referenced models. ^gNot applicable because the R-value only applies to the models.

The structure of the G6-OH(Pt₁₄₇@Cu_{full}) DENs is determined by fitting the XAS data, as described in the Experimental Section and then comparing the extracted CNs to the CNs calculated for model F1 and model F2 (Table 2 and Figure 6).

The following CNs were extracted from the fits to the in situ XAS data and compared to CNs calculated for the models: Pt–Pt (n_{PP}), Pt–Cu (n_{PC}), Cu–Pt (n_{CP}), Cu–Cu (n_{CC}), Pt–m (n_{Pm}), and Cu–m (n_{Cm}). Here, m is any metal (Pt or Cu) that is coordinated to Pt or Cu. The modeling approach assumes $n_{\text{Pm}} = n_{\text{PP}} + n_{\text{PC}}$ and $n_{\text{Cm}} = n_{\text{CC}} + n_{\text{CP}}$. The values of n_{Pm} and n_{Cm} essentially represent how coordinatively saturated the Pt and Cu atoms are relative to each other, and these are used to draw conclusions about DEN structure. We also extracted another CN from the experimental results, Cu–O (denoted n_{CO}), where –O is a low-z nearest neighbor (most likely H₂O, HSO₄[–], or SO₄^{2–}) on the Cu shell.⁴¹ It was necessary to include the Cu–O scattering path to accurately fit the experimental data, but we did not calculate a CN corresponding to n_{CO} for the models in Figure 6 because low-z neighbors were not included in these model structures.

Table 2 provides the extracted CNs for G6-OH(Pt₁₄₇@Cu_{full}), as well as the calculated CNs for 2 full-shell models: model F1 and model F2 (Figure 6). Model F1 is the previously described Pt₁₄₇@Cu_{full}^{DFT} model, in which Cu resides on the DEN facets. The structure represented by model F2 was constructed by performing MD simulations on model F1, and it shows the partial mixing of the Cu shell atoms with the Pt core.

The experimental value for n_{PP} (Table 2) was extracted from the data taken with the electrode poised at V_{full} and represents the average Pt–Pt CN for G6-OH(Pt₁₄₇@Cu_{full}). We found that the extracted value for n_{PP} (CN = 6.7 ± 1.1) is significantly lower than the calculated n_{PP} of model F1 (CN = 8.9): $n_{\text{PP}} = 8.9$ for a perfect 147-atom, cuboctahedral Pt cluster.⁴² Although the extracted n_{PP} underestimates the ideal value for the 147-atom Pt core, it is the same as the n_{PP} reported previously for Pt DENs of this size.^{27,28} There are several possible explanations for the discrepancy between the extracted and calculated n_{PP} values. First, we have previously shown that some Pt²⁺ remains within the dendrimer after reduction.²⁸ This will result in a lower-than-expected value for n_{PP} , because n_{PP} represents the ensemble average Pt–Pt CN for the entire sample and will therefore include contributions from both Pt atoms in the DENs and unreduced Pt²⁺ (CN = 0). To evaluate this possibility, we carried out XPS measurements on the Pt DENs used for the XAS analysis. The results of XPS measurements on

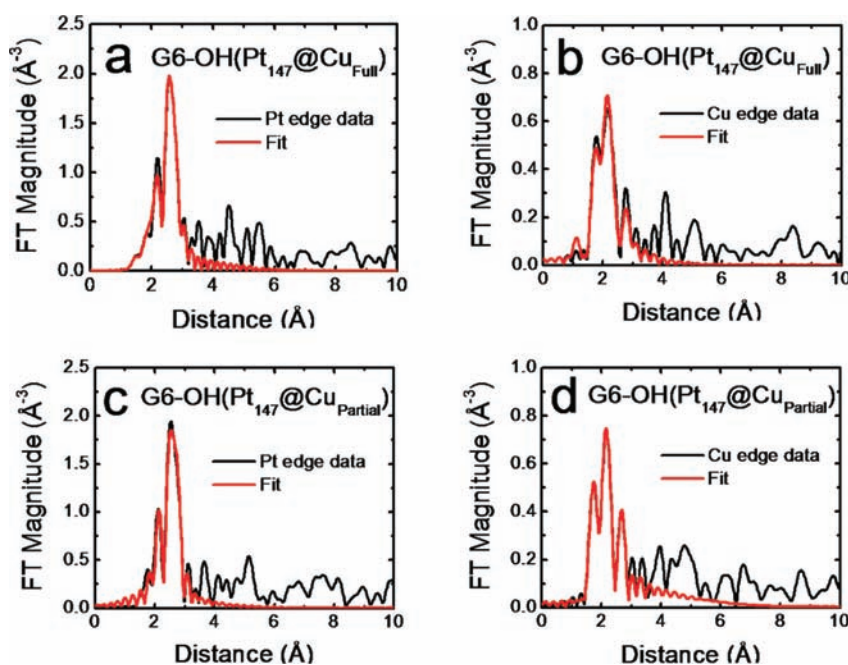


Figure 7. Radial distribution graphs of the in situ XAS data (black) and the computed fits (red) for (a and b) G6-OH(Pt₁₄₇@Cu_{full}) and (c and d) G6-OH(Pt₁₄₇@Cu_{partial}). These data were collected in a solution of 0.10 M H₂SO₄ with the electrode poised at V_{full} and $V_{partial}$ for G6-OH(Pt₁₄₇@Cu_{full}) and G6-OH(Pt₁₄₇@Cu_{partial}), respectively.

the G6-OH(Pt₁₄₇@Cu_{full}) confirmed the presence of a small fraction of unreduced Pt²⁺ (Supporting Information, Figure S9).

A second possible explanation for the lower-than-expected n_{pp} value could be partial alloying of some of the Cu shell atoms with the Pt atoms directly beneath them, as shown in model F2. As Cu atoms partition into the core, they displace some of the Pt atoms that reside in the first coordination shell of other Pt atoms, and therefore, on average, the Pt atoms in the DENs have fewer Pt nearest neighbors. However, we have made some observations which make it seem unlikely that model F2 is a viable representation of the actual DENs. Specifically, we noted earlier that the full Cu shell blocks H_{UPD} (Figure S5), which is not expected in the case of PtCu alloyed nanoparticles which have both Pt and Cu on their surfaces. With regard to this point, Strasser and co-workers³⁷ and Stevenson and co-workers³⁸ have shown that H_{UPD} does occur on PtCu alloy nanoparticles having just a fractional coverage of Pt atoms on the surface. Therefore, we believe that the blocking of H_{UPD} on the G6-OH(Pt₁₄₇@Cu_{full}) DENs provides good evidence that the Pt atoms in our DENs remain beneath the Cu shell and do not partition to the surface as depicted in model F2.

The extracted CNs for n_{PC} , n_{CP} , and n_{CC} are all in reasonable agreement with the values predicted for both the F1 and F2 models. However, from a modeling perspective, there are a few clear trends that distinguish core@shell nanoparticles from random atomic arrangements, such as alloys. For example, the value of n_{Cm} will be less than n_{Pm} for a core@shell particle, because Cu atoms confined to the surface of the nanoparticle will have fewer nearest neighbors than those occupying coordinatively saturated positions in the core.⁴³ We find that n_{Pm} is larger than n_{Cm} (Table 2) both for the experimentally extracted CNs and also for the CNs calculated for each of the models. Therefore, we postulate that the true structure of G6-OH(Pt₁₄₇@Cu_{full}) has a Pt rich core and a Cu-rich shell. As

mentioned earlier, even though the partially alloyed model is well matched to the XAS data, electrochemical experiments show that the Cu shell completely passivates the Pt surface against H_{UPD}, and thus, we conclude that model F1 is the most viable of the full shell models.

The bond distances and Debye–Waller factors for G6-OH(Pt₁₄₇@Cu_{full}) are provided in Table S1 in the Supporting Information. The Debye–Waller factors indicate greater disorder in all of the Cu–m bond pairs (n_{CC} , n_{CP}) compared to Pt–Pt bonds. This is indicative of segregation of the core and shell phases, because the atoms on the surface are considered to occupy high energy defect positions and tend to exhibit greater disorder than the coordinatively saturated atoms nearer the core.^{5,28} The average Pt–Pt bond distance (2.74 Å) is shorter than that of bulk Pt (2.77 Å). The contractile straining of the core phase may be attributed to surface tension.⁴⁴ The experimentally determined Cu–Cu bond distance (2.68 Å) exhibits a tensile strain due to lattice mismatch with the underlying Pt lattice. Cu monolayers on Pt will be template by the underlying Pt lattice, which has a larger lattice constant, and so the Cu–Cu bond distance is expanded.

The CNs extracted from the fits to the XAS data for G6-OH(Pt₁₄₇@Cu_{partial}) DENs are presented in Table 3 alongside the CNs for the partial shell model structures depicted in Figure 6. The bond lengths and Debye–Waller factors are provided separately (Supporting Information, Table S2). Reassuringly, n_{pp} is about the same regardless of whether there is a partial ($n_{pp} = 7.5 \pm 1.3$) or full ($n_{pp} = 6.7 \pm 1.1$) Cu shell present on the Pt core. The calculated CNs for the model structures (P1–P5, Figure 6) can be compared to the extracted CNs for the G6-OH(Pt₁₄₇@Cu_{partial}) DENs. Model P1 is the most likely partial shell model according to the DFT calculations, which preferentially positions the partial-shell Cu atoms on the Pt(100) facets. Model P2 illustrates the opposite case, in which Cu decorates the Pt(111) facets. Model P3 is a partial shell model in which the Cu shell exhibits Janus-like

coverage. On the basis of the experimental data and DFT calculations presented earlier, which served to demonstrate facet-selective Cu UPD behavior, it is unlikely that models P2 and P3 are correct, but we include them here for completeness.

Model P4 was constructed from model P1 by removing a few of the Cu atoms from the Pt(100) facets and placing them on Pt(111) facets. This could be a viable structure, because CV peaks for Cu UPD and stripping on the DENs (Figure 2, red line) overlap, indicating that stripping of the Cu atoms from one facet might not be complete before stripping from the other facet commences. In other words, some Cu atoms would still remain to be stripped from the Pt(111) facet when Cu atoms begin to strip from the Pt(100) facet. Model P5 is a partial shell model in which the Cu atoms are randomly distributed on the surface with no preference for one facet over the other. This model is an unlikely candidate, because it is incompatible with the results of our DFT studies, yet it was also included for comparison.

To determine which model provides the most favorable comparison to the experimental data, we calculated a correlation factor based on the calculated and extracted CNs and expressed this as the *R*-value in Table 3. The *R*-value, which is defined as the sum of the magnitude of differences between the extracted and calculated CNs, is used here to compare the models to the data, and to each other, to determine which model most closely approaches the experimentally characterized structure. The *R*-value was calculated according to eq 1.

$$R\text{-value} = \sum_{\text{CN}} \sqrt{\left(\frac{\text{CN}_{\text{extracted}} - \text{CN}_{\text{calculated}}}{\sigma} \right)^2} \quad (1)$$

Here, $\text{CN}_{\text{extracted}}$ values are CNs that were extracted from the fit to the data (n_{pp} , n_{PC} , n_{CC} , and n_{CP}) (“Extracted” in Table 3) and $\text{CN}_{\text{calculated}}$ values are the corresponding CNs for the model structures, and σ is the standard deviation for the extracted CNs. A lower correlation factor means a lesser overall magnitude of difference across all the CNs for the sample and the model and thus a better overall fit. This approach is exactly analogous to the sum of standardized *z*-scores in statistical analysis. The *R*-value for model P4 (3.8) (Table 3) was the lowest, and therefore, model P4 provides the best structural comparison to the experimental data. This model (P4) is in good agreement with our DFT studies, which showed that the stripping of the Cu from the Pt(100) facet did, in fact, commence before all of the Cu had stripped from the Pt(111) facet (Supporting Information, Figure S7), and thus, it is highly likely that this model could be close to the structure of the G6-OH(Pt₁₄₇@Cu_{partial}) DENs that were characterized by in situ XAS. Our earlier studies of H_{UPD} on G6-OH(Pt₁₄₇@Cu_{partial}) also support the facet-selective Cu UPD mechanism (Supporting Information, Figure S5b).

The analysis of XAS data corresponding to G6-OH(Pt₁₄₇@Cu_{full}) and G6-OH(Pt₁₄₇@Cu_{partial}) DENs suggests that Cu preferentially deposits on the Pt(100) facets: n_{CP} for G6-OH(Pt₁₄₇@Cu_{partial}) is close to 4, which would be the expected CN for Cu atoms residing in the 4-fold hollow positions. This is in agreement with XAS studies of Cu UPD on bulk Pt(100) single crystals. That is, Cu deposition is preferential for the Pt(100) orientation over the Pt(111) orientation.⁹

SUMMARY AND CONCLUSIONS

DENs are good model structures for comparing theory and experiment, because they are large enough to characterize experimentally but small enough to apply first-principles calculations. The present study represents our first effort to reconcile theory and experiment using a single model nanoparticle. Specifically, Pt DENs consisting of an average of 147 atoms and having a cuboctahedral structure were characterized in the presence and absence of full and partial monatomic Cu shells. Experimental observations by XPS, electrochemical methods, and in situ XAS were correlated to DFT calculations, and the results strongly suggest that Cu deposits primarily onto the Pt(100) facets of the DENs before deposition begins on the Pt(111) facets (Figure 6, model P4). This finding is consistent with previously reported results for Cu UPD onto bulk Pt single crystal electrodes.^{8–10} Perhaps the most meaningful result of the DFT studies was the finding that the presence of adsorbed SO₄ ligands produces results that compare more favorably to the experimental data than do the simple, naked DENs.

We are now turning our attention to a more complicated problem: the effect of full and partial UPD layers on electrocatalytic reactions. By decorating particular facets of DEN electrocatalysts with UPD layers, we hope to be able to influence the rates of reactions, such as the ORR, that are known to have crystallographic preferences. We are also quite interested in correlating theoretical and experimental results for core@shell DENs having full outer shells to better understand how the core influences catalytic reactions occurring on the shell metal. Findings for these studies will be reported in due course.

ASSOCIATED CONTENT

Supporting Information

A photograph of the electrochemical flow cell; cyclic voltammograms demonstrating the operation of the flow cell, oxidation of full and partial Cu UPD layers from Pt DENs, the hydrogen activity of Pt DENs with and without Cu UPD layers; TEM characterization of the Pt DENs; detailed view of the calculated UPD and stripping processes on naked and SO₄-coated Pt nanoparticles; *k*-space XAS data; XPS results obtained from Pt DENs; and tables of EXAFS results. This material is available free of charge via the Internet at <http://pubs.acs.org>.

AUTHOR INFORMATION

Corresponding Author

crooks@cm.utexas.edu; henkelman@mail.utexas.edu

Notes

The authors declare no competing financial interest.

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